

16-bit Constant Current LED Sink Driver

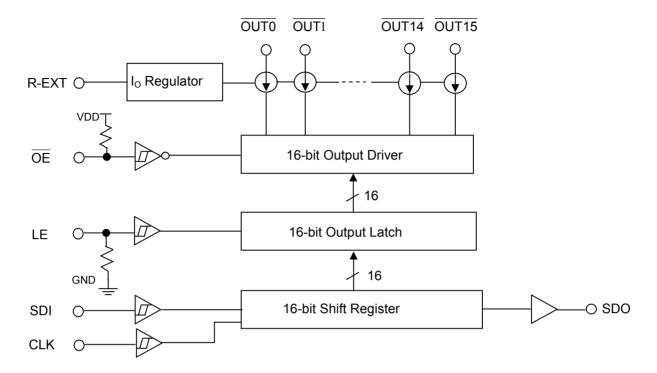
Features MBI5026CN\CNS 16 constant-current output channels Constant output current invariant to load voltage change Excellent output current accuracy: between channels: <±3% (max.), and CN: P-DIP24-300-2.54 between ICs: <±6% (max.) CNS: SP-DIP24-300-1.78 Output current adjusted through an external resistor Constant output current range: 5-90 mA MBI5026CD\CF Fast response of output current, OE (min.): 200 ns 25MHz clock frequency Schmitt trigger input 5V supply voltage CD: SOP24-300-1 27 CE: SOP24-300-1.00 MBI5026CP\CPA CP\CPA: SSOP24-150-0.64 **Current Accuracy** Conditions **Between Channels** Between ICs < ±3% < +6% $I_{OUT} = 10 \sim 60 \text{ mA}$

Product Description

MBI5026 is designed for LED displays. As an enhancement of its predecessor, MBI5016, MBI5026 exploits PrecisionDrive[™] technology to enhance its output characteristics. MBI5026 contains a serial buffer and data latches which convert serial input data into parallel output format. At MBI5026 output stage, sixteen regulated current ports are designed to provide uniform and constant current sinks for driving LEDs within a large range of Vf variations.

MBI5026 provides users with great flexibility and device performance while using MBI5026 in their system design for LED display applications, e.g. LED panels. Users may adjust the output current from 5 mA to 90 mA through an external resistor, R_{ext}, which gives users flexibility in controlling the light intensity of LEDs. MBI5026 guarantees to endure maximum 17V at the output port. The high clock frequency, 25 MHz, also satisfies the system requirements of high volume data transmission.

Block Diagram



Terminal Description

Pin Name	Function			
GND	Ground terminal for control logic and current sink			
SDI	Serial-data input to the shift register			
CLK	Clock input terminal for data shift on rising edge			
	Data strobe input terminal			
LE	Serial data is transferred to the output latch when LE is high. The data is latched when LE goes low.			
OUT0~OUT15	Constant current output terminals			
	Output enable terminal			
ŌĒ	When \overline{OE} (active) low, the output drivers are enabled; when \overline{OE} high, all output drivers are turned OFF (blanked).			
SDO	Serial-data output to the following SDI of next driver IC			
R-EXT	Input terminal used to connect an external resistor for setting up output current for all output channels			
VDD	5V supply voltage terminal			

Pin Configuration

GND	1	Ш	24	VDD
SDI	2		23	R-EXT
CLK	3		22	SDO
LE 📕	4		21	OE
OUT0	5		20	OUT15
OUT1	6		19	OUT14
OUT2	7		18	OUT13
OUT3	8		17	OUT12
OUT4	9		16	OUT11
OUT5	10		15	OUT10
OUT6	11		14	OUT9
OUT7	12		13	■ OUT8
	L			1

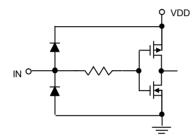
MBI5026CN\CNS\CD\CF\CP

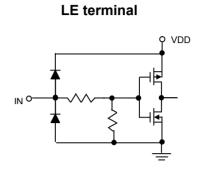
OUT14	1	⊔ ₂₄	OUT13		
OUT15	2	23	OUT12		
OE	3	22	OUT11		
SDO	4	21	OUT10		
R-EXT	5	20	OUT9		
VDD	6	19	OUT8		
GND	7	18	OUT7		
SDI	8	17	OUT6		
CLK	9	16	OUT5		
LE	10	15	OUT4		
OUT0	11	14	OUT3		
OUT1	12	13	OUT2		
MBI5026CPA					

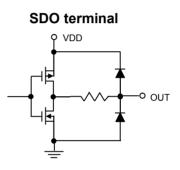
Equivalent Circuits of Inputs and Outputs

OE terminal

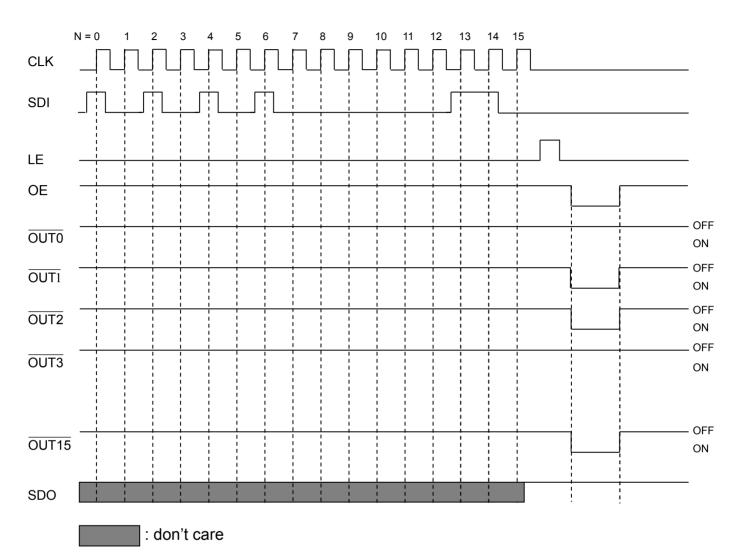








Timing Diagram



Truth Table

CLK	LE	ŌE	SDI	OUT0 OUT7 OUT15	SDO
	Н	L	D _n	$\overline{Dn} \dots \overline{Dn-7} \dots \overline{Dn-15}$	D _{n-15}
	L	L	D _{n+1}	No Change	D _{n-14}
	Н	L	D _{n+2}	$\overline{Dn+2}$ $\overline{Dn-5}$ $\overline{Dn-13}$	D _{n-13}
	Х	L	D _{n+3}	$\overline{Dn+2}$ $\overline{Dn-5}$ $\overline{Dn-13}$	D _{n-13}
_	Х	Н	D _{n+3}	Off	D _{n-13}

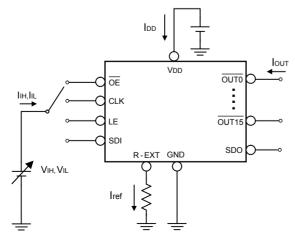
Maximum Ratings

Characte	eristic	Symbol	Rating	Unit
Supply Voltage		V _{DD}	0~7.0	V
Input Voltage		V _{IN}	-0.4~V _{DD} + 0.4	V
Output Current		I _{OUT}	+90	mA
Output Voltage		V _{DS}	-0.5~+20.0	V
Clock Frequency		F _{CLK}	25	MHz
GND Terminal Current		I _{GND}	1440	mA
	CN – type		2.32	
	CNS – type		1.87	
Power Dissipation	CD – type	– P _D	2.51	W
(On PCB, Ta=25°C)	CF – type	гD	2.12	vv
	CP – type		1.73	
	CPA – type		1.73	
	CN – type		53.82	
	CNS – type		66.74	
Thermal Resistance	CD– type	P	49.81	°C/W
(On PCB, Ta=25°C)	CF – type	– R _{th(j-a)}	59.01	0/00
	CP – type		72.43	
	CPA – type		72.43	
Operating Temperature		T _{opr}	-40~+85	°C
Storage Temperature		T _{stg}	-55~+150	°C

Electrical Characteristics

Charac	Characteristic		Condition		Min.	Тур.	Max.	Unit
Supply Voltag	е	V _{DD}	-		4.5	5.0	5.5	V
Output Voltag	е	V _{DS}	OUTO~ OUT15		-	-	17.0	V
		Ι _{ουτ}	DC Test Circuit		5	-	90	mA
Output Current	t	I _{ОН}	SDO		-	-	-1.0	mA
			SDO		-	-	1.0	mA
	"H" level	V _{IH}	Ta = -40~85°C		0.8V _{DD}	-	V _{DD}	V
Input Voltage	"L" level	V _{IL}	Ta = -40~85°C		GND	-	$0.3V_{\text{DD}}$	V
Output Leakag	e Current	I _{OH}	V _{OH} =17.0V		-	-	0.5	μA
Output Voltage	e SDO	V _{OL}	I _{OL} =+1.0mA		-	-	0.4	V
	; 300	V _{OH}	I _{OH} =-1.0mA		4.6	-	-	V
Output Current	t 1	I _{OUT1}	V _{DS} =0.6V	R _{ext} =720 Ω	-	26.25	-	mA
Current Skew		dl _{out1}	I _{OL} =26.25mA V _{DS} =0.6V	R _{ext} =720 Ω	-	±1	±3	%
Output Current	t 2	I _{OUT2}	V _{DS} =0.8V R _{ext} =360 Ω		-	52.5	-	mA
Current Skew		dl _{out2}	I _{OL} =52.5mA V _{DS} =0.8V R _{ext} =360 Ω		-	±1	±3	%
Output Current Output Voltage		%/dV _{DS}	V_{DS} within 1.0V and 3.0V		-	±0.1	-	% / V
Output Current Supply Voltage		%/dV _{DD}	V _{DD} within 4.5V a	and 5.5V	-	±1	-	% / V
Pull-up Resisto	or	R _{IN} (up)	ŌĒ		250	500	800	KΩ
Pull-down Res	istor	R _{IN} (down)	LE		250	500	800	KΩ
	I _{DD} (off) 1 R _{ext} =Open, OUTO ~		0 ∼ OUT15 =Off	-	7	12		
"OFF"	I _{DD} (off) 2	R _{ext} =720 Ω, <u>OUT0</u> ~ <u>OUT15</u> =Off		-	- 10 1	12		
Supply Current		I _{DD} (off) 3	R_{ext} =360 Ω , $\overline{OUT0} \sim \overline{OUT15}$ =Off		-	12	15	mA
	"ON"	I _{DD} (on) 1	R _{ext} =720 Ω, <u></u> 001	ro ~ OUT15 =On	-	10	18	
	UN	I _{DD} (on) 2	R _{ext} =360 Ω, <u></u> 001	ro ~ OUT15 =On	-	12	20	

Test Circuit for Electrical Characteristics

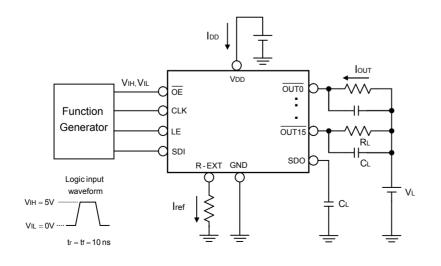


Switching Characteristics

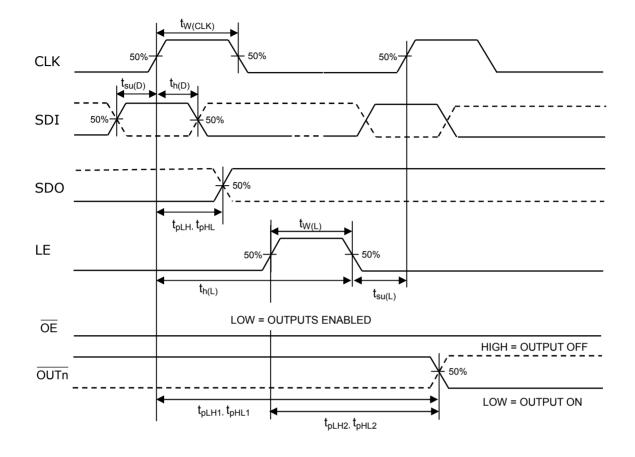
Characteristic		Symbol	Condition	Min.	Тур.	Max.	Unit
	CLK - OUTn	t _{pLH1}		-	50	100	ns
Propagation Delay Time	LE - OUTn	t _{pLH2}		-	50	100	ns
("L" to "H")	OE - OUTn	t _{pLH3}		-	20	100	ns
	CLK - SDO	t _{pLH}		15	20	-	ns
	CLK - OUTn	t _{pHL1}	V _{DD} =5.0 V V _{DS} =0.8 V	-	100	150	ns
Propagation Delay Time	LE - OUTn	t _{pHL2}	V _{IH} =V _{DD}	-	100	150	ns
("H" to "L")	OE - OUTn	t _{pHL3}	V _{IL} =GND R _{ext} =300 Ω	-	50	150	ns
	CLK - SDO	t _{pHL}	V _L =4.0 V R _L =52 Ω	15	20	-	ns
	CLK	t _{w(CLK)}	C _L =10 pF	20	-	-	ns
Pulse Width	LE	t _{w(L)}		20	-	-	ns
	ŌĒ	t _{w(OE)}		200	-	-	ns
Hold Time for LE		t _{h(L)}		5	-	-	ns
Setup Time for LE		t _{su(L)}		5	-	-	ns
Hold Time for SDI		t _{h(D)}		10	-	-	ns
Setup Time for SDI		t _{su(D)}		5	-	-	ns
Clock Frequency		F _{CLK}	Cascade Operation	-	-	25.0	MHz
Maximum CLK Rise Time		tr**		-	-	500	ns
Maximum CLK Fall Time		t _f **		-	-	500	ns
Output Rise Time of Vout (Output Rise Time of Vout (turn off)			-	40	120	ns
Output Fall Time of Vout (t	urn on)	t _{of}		-	70	200	ns

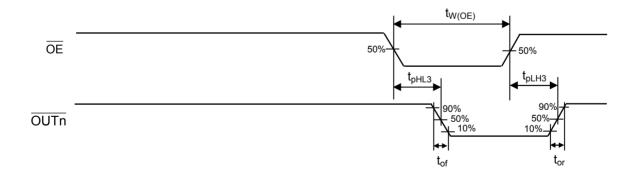
**If the devices are connected in cascade and t_r or t_f is large, it may be critical to achieve the timing required for data transfer between two cascaded devices.

Test Circuit for Switching Characteristics



Timing Waveform



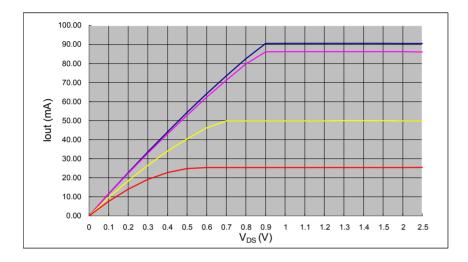


Application Information

Constant Current

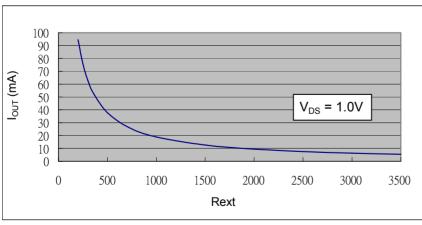
In LED display application, MBI5026 provides nearly no variations in current from channel to channel and from IC

- to IC. This can be achieved by:
- 1) The maximum current variation between channels is less than $\pm 3\%$, and that between ICs is less than $\pm 6\%$.
- 2) In addition, the current characteristic of output stage is flat and users can refer to the figure as shown below. The output current can be kept constant regardless of the variations of LED forward voltages (Vf). This performs as a perfection of load regulation.



Adjusting Output Current

The output current of each channel (I_{OUT}) is set by an external resistor, R_{ext} . The relationship between I_{out} and R_{ext} is shown in the following figure.



Resistance of the external resistor, R_{ext} in Ω

Also, the output current can be calculated from the equation:

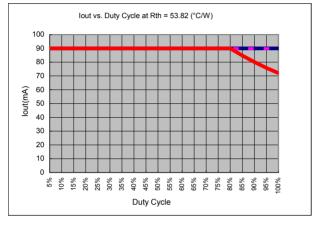
 $V_{\text{R-EXT}}$ = 1.26V ; I_{OUT} = (V_{\text{R-EXT}} / R_{\text{ext}}) x 15

where R_{ext} is the resistance of the external resistor connected to R-EXT terminal and V_{R-EXT} is the voltage of R-EXT terminal. The magnitude of current (as a function of R_{ext}) is around 52.5mA at 360 Ω and 26.25mA at 720 Ω .

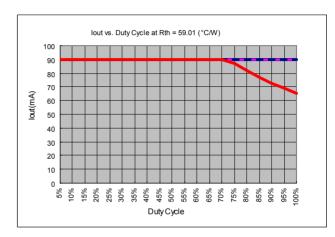
Package Power Dissipation (P_p)

The maximum allowable package power dissipation is determined as $P_D(max) = (Tj - Ta) / R_{th(j-a)}$. When 16 output channels are turned on simultaneously, the actual package power dissipation is $P_D(act) = (I_{DD} \times V_{DD}) + (I_{OUT} \times Duty)$ x V_{DS} x 16). Therefore, to keep $P_D(act) \le P_D(max)$, the allowable maximum output current as a function of duty cycle is:

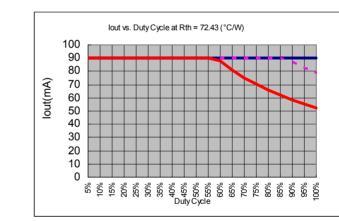
 $I_{OUT} = \{ [(Tj - Ta) / R_{th(i-a)}] - (I_{DD} \times V_{DD}) \} / V_{DS} / Duty / 16, \}$ where Tj = 150°C.



CN type package



CF type package

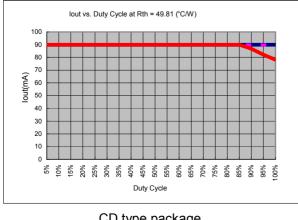


CP\CPA type package

Condition : $I_{out} = 90 \text{mA}$, $V_{DS} = 1.0 \text{V}$, 16 output					
	channels activ	e			
Device Type	R _{th(j-a)} (°C/W)	Note			
CN	53.82				
CNS	66.74	Ta = 25℃			
CD	49.81	Ta = 55℃			
CF	59.01	Ta = 85℃			
CP\CPA	72.43				

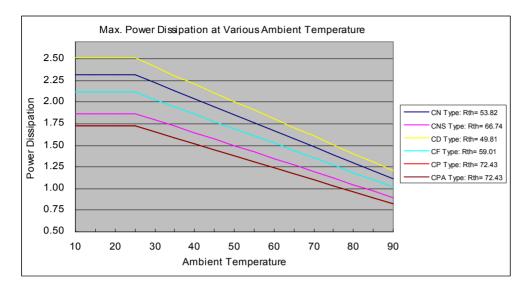
lout vs. Duty Cycle at Rth = 66.74 (°C/W) 100 90 80 70 lout(mA) 60 50 40 30 20 10 0 5% 10% 20% 25% 30% 35% 40% 45% 50% 55% 60% 65% 70% 85% 90% 95% 00% 75% 80% Duty Cycle

CNS type package



CD type package

The maximum power dissipation, $P_D(max) = (Tj - Ta) / R_{th(j-a)}$, decreases as the ambient temperature increases.

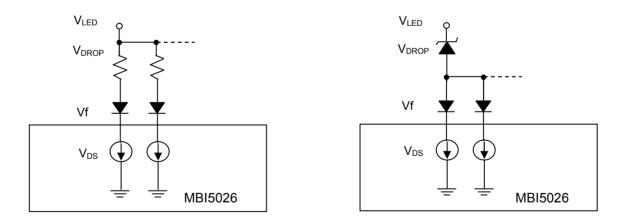


Load Supply Voltage (V_{LED})

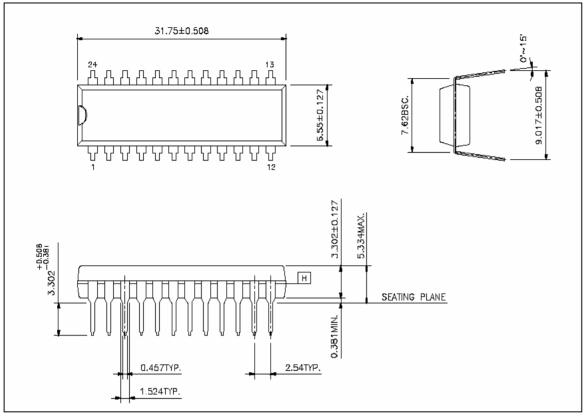
MBI5026 are designed to operate with V_{DS} ranging from 0.4V to 1.0V considering the package power dissipating limits. V_{DS} may be higher enough to make $P_{D(act)} > P_{D(max)}$ when $V_{LED} = 5V$ and $V_{DS} = V_{LED} - Vf$, in which V_{LED} is the load supply voltage. In this case, it is recommended to use the lowest possible supply voltage or to set an external voltage reducer, V_{DROP} .

A voltage reducer lets V_{DS} = ($V_{LED} - Vf$) – V_{DROP} .

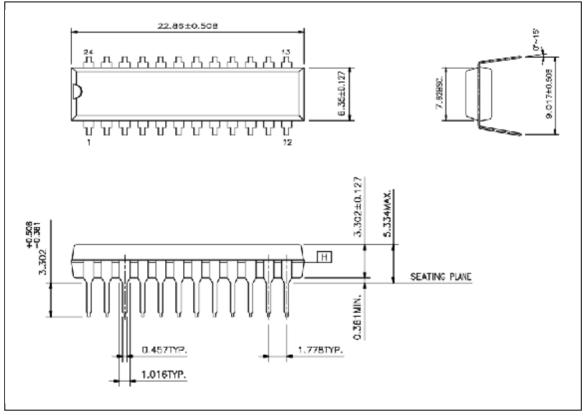
Resistors or Zener diode can be used in the applications as shown in the following figures.



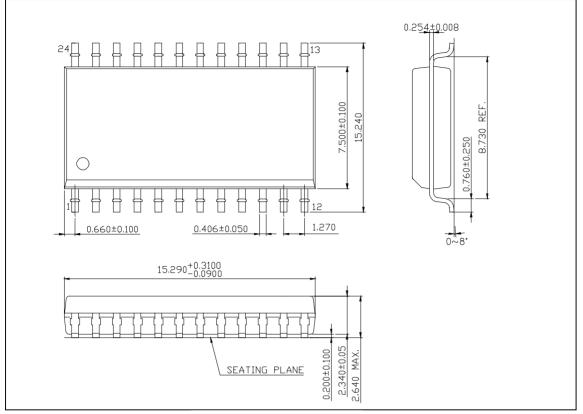
Package Outline



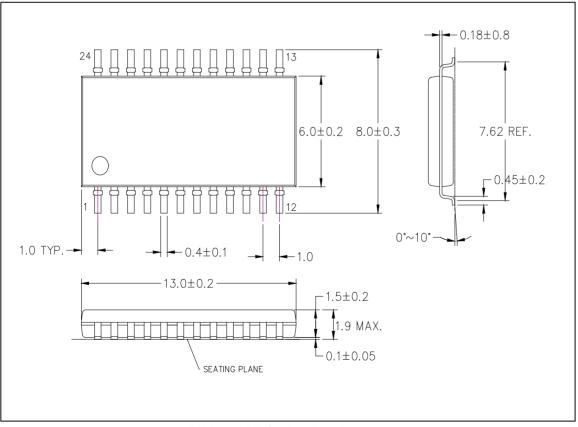
MBI5026CN Outline Drawing



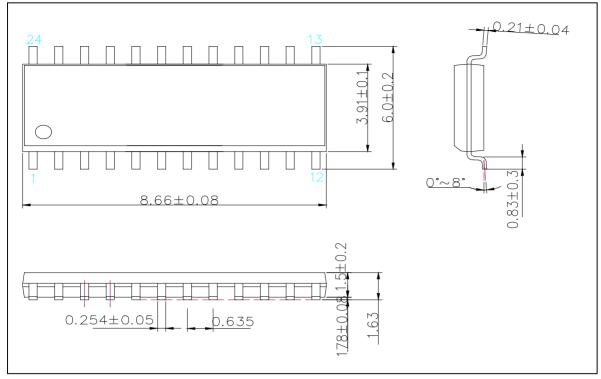
MBI5026CNS Outline Drawing



MBI5026CD Outline Drawing



MBI5026CF Outline Drawing



MBI5026CP\CPA Outline Drawing

MBI5026 Package Information

Device Type	Package Type	Weight(g)
CN	P-DIP24-300-2.54	1.628
CNS	SP-DIP24-300-1.78	1.11
CD	SOP24-300-1.27	0.617
CF	SOP24-300-1.00	0.28
CP\CPA	SSOP24-150-0.64	0.11

Note: The unit for the outline drawing is mm.

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